

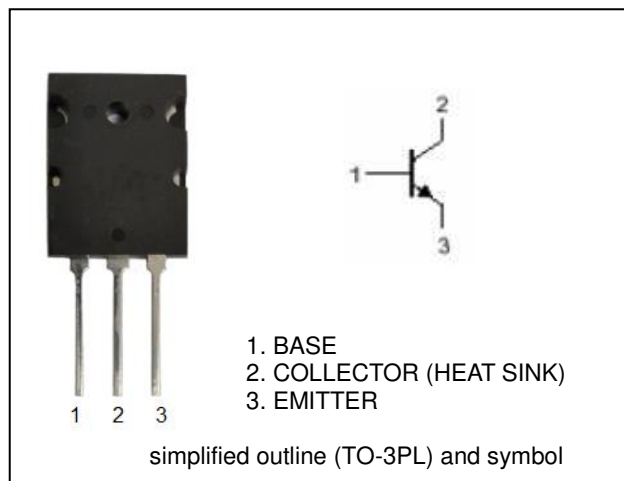
Silicon NPN Power Transistors

DESCRIPTION

- High Collector-Emitter Breakdown Voltage-
: $V_{(BR)CEO} = 230V(\text{Min})$
- Complement to Type 2SA1943

APPLICATIONS

- Power amplifier applications
- Recommend for 100W high fidelity audio frequency amplifier output stage applications



MAXIMUM RATINGS

Characteristic	Symbol	2SC5200	Unit
Collector-Base Voltage	V_{CBO}	230	V
Collector-Emitter Voltage	V_{CEO}	230	V
Emitter-Base Voltage	V_{EBO}	5	V
Collector Current	I_C	15	A
Base current	I_B	1.5	A
Collector power dissipation @ $T_C=25^\circ\text{C}$	P_C	150	W
Junction Temperature	T_j	150	$^\circ\text{C}$
Storage Temperature Range	T_{stg}	-65 to +150	$^\circ\text{C}$

ELECTRICAL CHARACTERISTICS ($T_C=25^\circ\text{C}$ unless otherwise notes)

Characteristic	Symbol	Min.	Typ.	Max.	Unit
Collector-Emitter Breakdown Voltage ($I_C = 50 \text{ mA}$, $I_B = 0$)	V_{CEO}	230			V
Collector Cutoff Current ($V_{CB} = 230 \text{ V}$, $I_E = 0 \text{ V}$)	I_{CBO}			5	μA
Emitter Cutoff Current ($V_{EB} = 5.0 \text{ V}$, $I_C = 0$)	I_{EBO}			5	μA
DC Current Gain ($I_C = 1.0 \text{ A}$, $V_{CE} = 5.0 \text{ V}$)	$h_{FE(1)}$ (Note)	55		160	
DC Current Gain ($I_C = 7.0 \text{ A}$, $V_{CE} = 5.0 \text{ V}$)	$h_{FE(2)}$	35			
Collector-Emitter Saturation Voltage ($I_C = 8.0 \text{ A}$, $I_B = 0.8 \text{ A}$)	$V_{CE(SAT)}$			3.0	V
Base-Emitter On Voltage ($I_C = 7.0 \text{ A}$, $V_{CE} = 5.0 \text{ V}$)	$V_{BE(ON)}$			1.5	V
Output Capacitance ($I_E = 0$, $V_{CB} = 10 \text{ V}$, $f = 1.0 \text{ MHz}$)	C_{OB}		200		pF
Current-Gain—Bandwidth Product ($I_C = 1 \text{ A}$; $V_{CE} = 5 \text{ V}$)	f_T		30		MHz

Note : $h_{FE(1)}$ Classifications R : 55~110 , O : 80~160

FIG-1 I_C - V_{CE} CHARACTERISTICS

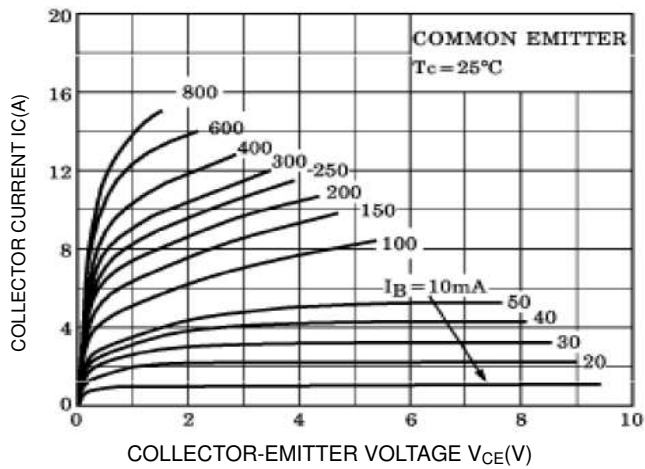


FIG-2 I_C - V_{BE} CHARACTERISTICS

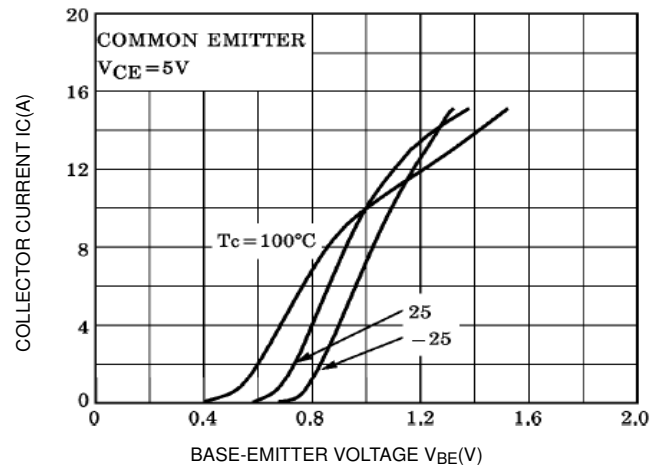


FIG-3 $V_{CE(\text{SAT})}$ - I_C CHARACTERISTICS

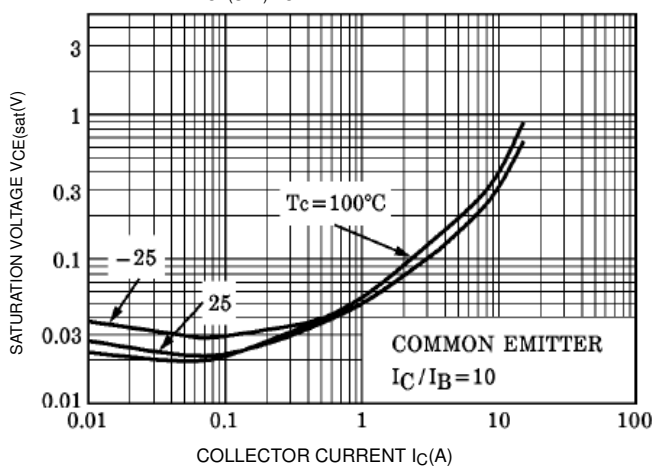


FIG-4 h_{fe} - I_C CHARACTERISTICS

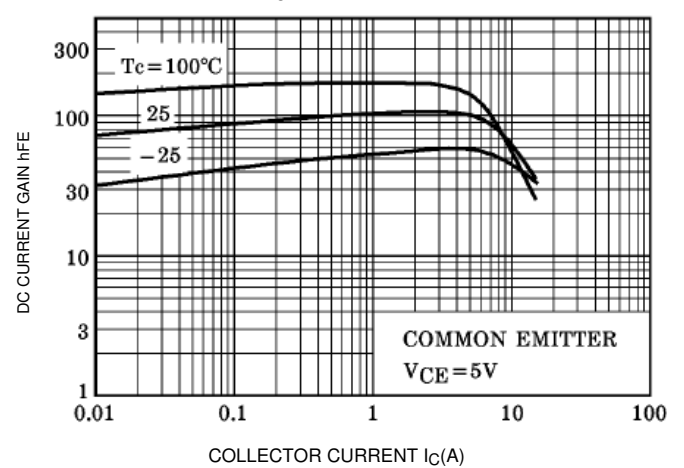
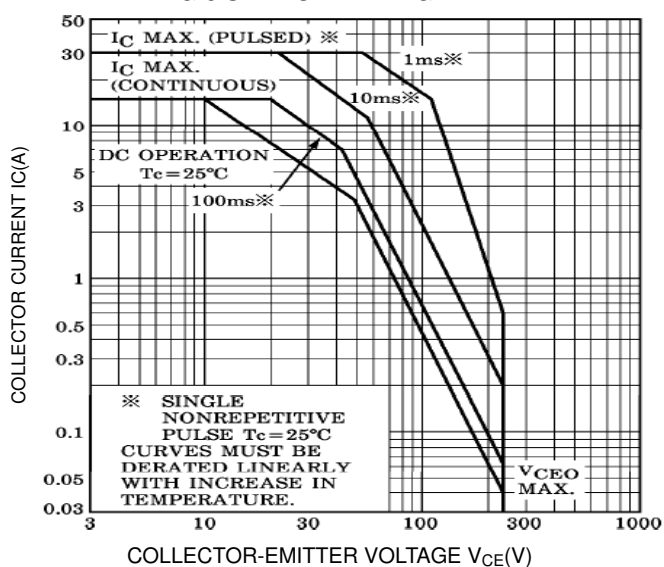
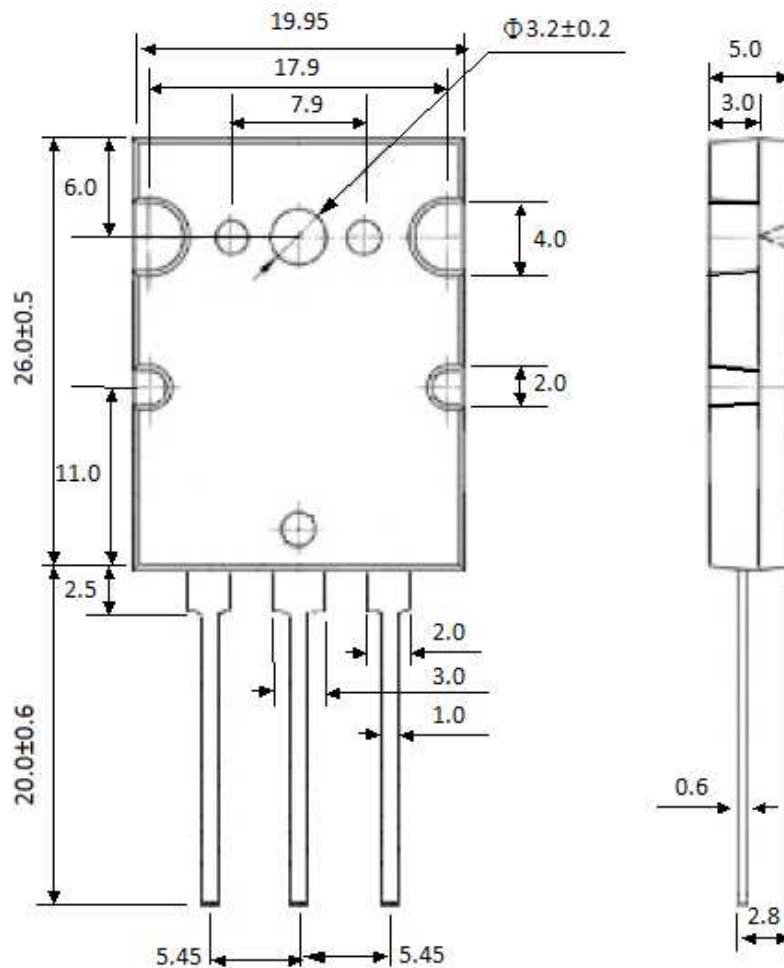


FIG-5 SAFE OPERATING AREA



PACKAGE OUTLINE DIMENSIONS (Unit in mm)

TO-3PL



Notice

MOSPEC reserves the rights to make changes of the content herein the document anytime without notification. MOSPEC or anyone on its behalf, assumes no responsibility or liability for any errors or inaccuracies. Please refer to MOSPEC website for the last document.

MOSPEC disclaims any and all liability arising out of the application or use of any product including damages incidentally and consequentially incurred.

Application shown on the herein document are examples of standard use and operation. Customers are responsible for comprehending suitable use in particular applications. MOSPEC makes no representation or warranty that such application will be suitable for the specified use without further testing or modification.

The information contained herein is presented only as a guide for the applications of our products. No responsibility is assumed by MOSPEC for any infringements of patents or other rights of the third parties which may result from its use. No license is granted by implication or otherwise under any patent or patent rights of MOSPEC or others.

These MOSPEC products are intended for usage in general electronic equipment. Please make sure to consult with MOSPEC before you use these MOSPEC products in equipment which require specialized quality and/or reliability, and in equipment which could have major impact to the welfare of human life (atomic energy control, aeronautics , traffic control, combustion control, safety devices etc.)